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# Resistivity and magnetoresistance of CeAl<sub>3</sub> single crystals

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In honor of Martin Peter's 60th birthday.

Abstract. We discuss the anisotropic resistivity of single crystalline CeAl<sub>3</sub>. At low temperature, both the resistivity and the magnetoresistance provide evidence that some kind of magnetic order starts to develop at 1.6 K. At very low temperature, the residual resistivity rapidly decreases as temperature increases with approximately the same characteristic temperature which governs the pure Kondo lattice resistivity.

### Introduction

Among the heavy fermion compounds (HFC),  $CeAl_3$  is one of the most studied. Its ground state was characterized as normal conducting and paramagnetic [1] and it was considered as archetype of non magnetic HFC. However, the peritectoidic formation of this compound at 1135 K prevents the growth of the large single crystals necessary for studying carefully the nature of the ground state. To overcome this difficulty we developed an experimental set up for transport properties measurements on the very small single crystals one can extract from an annealed polycrystalline ingot. At the same time we started to anneal different Ce-Al alloys under very high vacuum in order to obtain the largest single crystalline grains by recrystallization. The temperature dependence of the resistivity was measured on two samples with current parallel or perpendicular to the hexagonal c-axis. Longitudinal and transverse magnetoresistances were also measured. Details about the samples and the measurement technique can be found in Ref. 2.

## Resistivity

Figure 1 shows the temperature dependence of the resistivity of a  $CeAl_3$  single crystal with the current I parallel or perpendicular to the hexagonal c-axis. Along both directions the resistivity exhibits a maximum around 35 K. From these

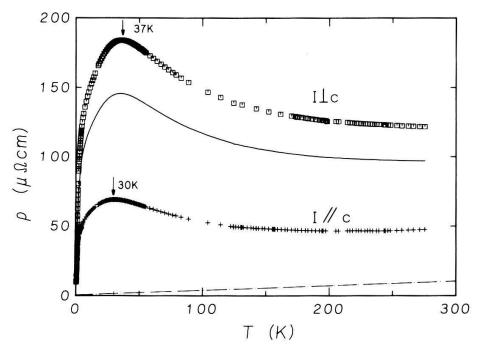


Figure 1 Temperature dependence of the resistivity of CeAl<sub>3</sub> single crystals with the current parallel or perpendicular to the c-axis. Solid line: calculated resistivity  $\rho = \frac{1}{3} \ (\rho_{\parallel} + 2\rho_{\perp})$  of a polycrystal. Dotted-dashed line: normal phonon contribution estimated from LuAl<sub>3</sub> measurements [5].

results one can calculate the polycrystalline resistivity curve  $\rho = \frac{1}{3} (\rho_{\parallel} + 2\rho_{\perp})$  shown as a solid line on the figure, in very good agreement with the previous experimental results of Ref. 3.

The ln T variation of the resistivity, often considered as a signature of single ion Kondo coupling, is followed here in a rather narrow temperature range  $(50 \le T \le 90 \text{ K})$ . In fact, as pointed out in Ref. 4, a better fit of our data can be obtained up to room temperature according to an empirical law  $\rho = aT + bT^{-1/2}$ , but the phonon term aT is larger than that extracted from the resistivity measurements of polycrystalline isostructural LuAl<sub>3</sub> [5].

Figure 1 also shows that  $\rho_{\perp}$  is larger than  $\rho_{\parallel}$ , indicating a stronger scattering in the basal plane than along the c-axis. This agrees with single ion Kondo theory for a highly anisotropic ground state of the 4f electron [6, 7]. In such theory the resistivity along the c-axis is small if the crystal electric field (CEF) ground state is a doublet constructed from the  $|J_z=\pm\frac{5}{2}\rangle$  and/or  $|J_z=\pm\frac{3}{2}\rangle$  states and the CEF splitting  $\Delta$  is large. For infinite  $\Delta$  the parallel resistivity is even zero. However, neutron scattering experiments [8, 9] indicate an overall CEF splitting  $\Delta \cong 90$  K and consequently the anisotropy of  $\rho$  should strongly decrease for  $T > \Delta$  as observed for instance in CeCu<sub>2</sub>Si<sub>2</sub> [10].

So, the most intriguing feature in Fig. 1 is the nearly temperature independent ratio  $\rho_{\perp}/\rho_{\parallel} \cong 3$  for T > 10 K. This probably originates in the anisotropy of the coupling constant J of 4f electrons with the Fermi sea, not taken into account by the theory.

It can be seen in Fig. 2 that for  $T < 4 \,\mathrm{K}$  the anisotropy of  $\rho_{\perp}$  and  $\rho_{\parallel}$  rapidly decreases and that, below  $0.6 \,\mathrm{K}$ ,  $\rho_{\parallel}$  even becomes larger than  $\rho_{\perp}$ . The break of

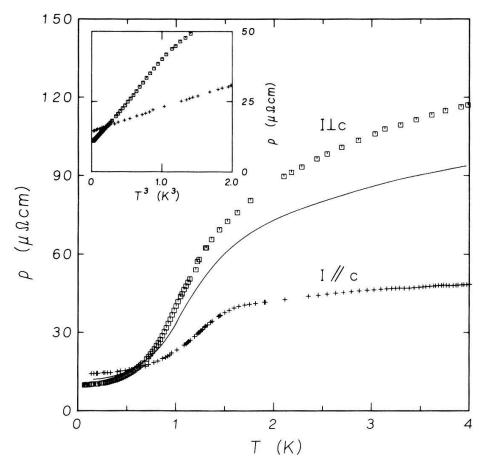


Figure 2 Low temperature dependence of the resistivity of CeAl<sub>3</sub> single crystals with the current parallel or perpendicular to the c-axis. The insert shows the  $T^3$  variation. Solid line: see Fig. 1.

 $ho_{\parallel}$  at 1.6 K with no corresponding anomaly in  $ho_{\perp}$  is rather unexpected. Recent muon spin resonance experiments [11] seem to indicate at nearly the same temperature  $(T=1.5 \, \text{K})$  the development of short range magnetic correlations between the 4f electron moments. Also surprising for a non magnetic HFC are the  $T^3$  variations of  $ho_{\perp}$  and  $ho_{\parallel}$  for  $0.4 < T < 1 \, \text{K}$  (insert of Fig. 2).

Usually, in this temperature range, the resistivity of HFC, such as  $CeCu_2Si_2$ ,  $CeCu_6$  or polycrystalline  $CeAl_3$ , shows approximate linear (or even less rapid) T dependence.  $T^n$  power laws with n > 2 are reminiscent of electron magnon scattering and have been observed in antiferromagnetic ordered Kondo compounds such as  $CeAl_2$  (n = 3) [12, 13] and  $CeB_6$  (n = 3.5) [14].

Below 0.35 K, the resistivity  $\rho_{\perp}$  and  $\rho_{\parallel}$  both recover the standard law  $\rho = \rho_0 + AT^2$  expected for a strongly interacting Fermi liquid but with much higher residual resistivity values  $\rho_0$  and lower A coefficients than in polycrystalline samples (see Table 1). In spite of these discrepancies, the temperature range where the resistivity follows a  $T^2$  law is the same for both single and polycrystal. In fact, the disagreement between the calculated resistivity  $\rho_{\text{poly}}^{\text{cal}} = \frac{1}{3}(\rho_{\parallel} + 2\rho_{\perp})$  of a polycrystal and the experimental values  $\rho_{\text{poly}}^{\text{exp}}$  is large only for T < 1 K. Therefore, it appears that the difference  $\Delta \rho_{\text{imp}} = \rho_{\text{poly}}^{\text{cal}} - \rho_{\text{poly}}^{\text{exp}}$ , identified as an impurity contribution, decreases as  $T^2$  up to 0.35 K. From Table 1 this

Table 1 Residual resistivity  $\rho_0$ , quadratic A and cubic B temperature coefficients of the resistivity for CeAl<sub>3</sub> single crystals and various polycrystals.

	$ ho_0 (\mu \Omega  ext{ cm})$	$A (\mu\Omega \text{ cm/K}^2)$	$B (\Omega \text{ cm/K}^3)$
$I\perp c$	9.9	13.3	30
$I \parallel c$	14.5	4.6	8
polyc (15)	2.0	32.0	-
polyc (15)	5.0	30	
polyc(1)	0.7	35	
polyc (14)	3.8	29	

impurity contribution can be written for T < 0.35 K as

$$\Delta \rho_{\rm imp} \cong (10 - 20T^2)\mu\Omega$$
 cm

or put in another form

$$\Delta \rho \cong 10\{1 - [T/(0.7 \text{ K})]^2\} \mu \Omega \text{ cm}$$
 (1)

to underline the impurity scale temperature  $T_i$  of 0.7 K.

A similar behavior has been observed in (Ce, La)Pd<sub>3</sub> but with a higher scale temperature of about 30 K and has been interpreted by scattering of heavy quasiparticles from Kondo hole when the system is in its coherent regime [16]. However, apart from the resistivity, the other physical properties (magnetic susceptibility, specific heat) do not show clear evidence of the Kondo hole mechanism.

Another interpretation has been given by Fetisov and Khomskiì [17] assuming that impurities induce scattering from the light d band to the heavy f band in complete analogy with the two band models for d transition metals. In this scheme the impurity resistivity takes the form

$$\rho_{\rm imp} = \rho_0 [1 - (\pi^2/3)(T/T_f)^2] \tag{2}$$

where  $T_f$  is the scale temperature of the pure system. To evaluate  $T_f$  from the  $T^2$  law of pure CeAl<sub>3</sub>, we note that the resistivity should reach its saturation value  $\rho_s$  as  $\rho(T) \cong \rho_s(T/T_f)^2$ . Taking  $\rho(T_{\text{max}}) = 150 \,\mu\Omega$  cm as an estimate of  $\rho_s$ , we obtain  $T_f \cong 2.3$  K. From equation (1) and (2), the relation between the scale temperatures  $T_i$  and  $T_f$  of the impurity and pure systems is quite natural.

Furthermore, according to Fetisov and Khomskii, the second term in (2) renormalizes the coefficient  $A_p$  of the  $T^2$  law of the pure lattice. So the experimental term is

$$A_{\rm exp} = A_p - (\pi^2/3)(\rho_0/T_f^2)$$

This nicely agrees with the values listed in Table 1. Figure 3 shows that  $A_{\rm exp}$ , as a function of  $\rho_0$ , fits a straight line which slope gives  $T_f \cong 1.2 \, \rm K$ . Evidently,  $A_p \cong 37 \, \mu\Omega \, \rm cm/K^2$  can also be extrapolated as  $\rho_0 \to 0$ .

Finally, we want to note that the impurity resistivity should be associated with a positive contribution of the thermoelectric power located at a temperature

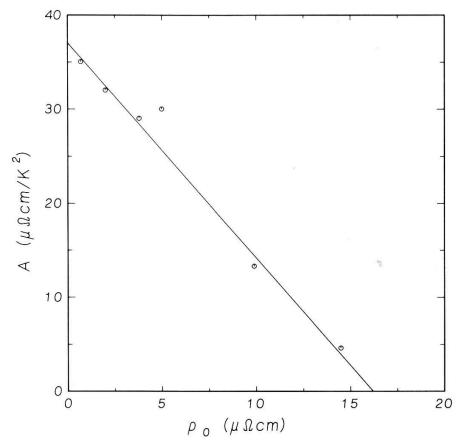


Figure 3 Values listed in Table 1 of the coefficient A in the law  $\rho = \rho_0 + AT^2$  as a function of the residual resistivity  $\rho_0$ .

somewhat below  $T_f$  as observed in CeAl<sub>3</sub> [15] and CePd<sub>3</sub> [18]. This mechanism also explains why the largest thermoelectric power has been measured for samples with high residual resistivity values in apparent contradiction to the Nordheim-Gorter rule [15].

# Magnetoresistance

Let us now discuss the magnetic field dependence of the low temperature resistivity. Results for  $I \parallel c$  and  $H \parallel c$  are reported in Fig. 4.

Above 2 K, the magnetoresistance  $\Delta \rho/\rho$  is negative for H parallel to c whatever the direction of the current ( $\parallel$  or  $\perp$  c), whereas  $\Delta \rho/\rho$  is positive but very weak for  $H \perp c$ . Usually, the negative magnetoresistance is characteristic for the presence of local magnetic moments [19]. The anisotropic magnetic field response of the resistivity agrees with predictions of Ref. 6 and confirms the doublet  $|J_z = \pm 3/2\rangle$  ground state in CeAl<sub>3</sub>.

At very low temperature, the resistivity is dominated by its residual value  $\rho_0$ . It can be seen in Fig. 4 that the magnetoresistance for  $I \parallel c$  and  $H \parallel c$  is positive up to 8 T and exhibits a large maximum at a field  $H_{\text{max}} \cong 2.2 \text{ T}$ .

In polycrystalline samples similar results have been observed with the same field  $H_{\text{max}}$  but with  $\Delta \rho / \rho$  values lower by a factor of about 4 [15, 20, 21]. This

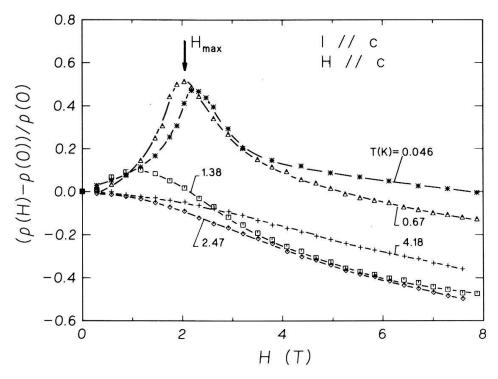


Figure 4 Longitudinal magnetoresistance along the c-axis of CeAl<sub>3</sub> at different low temperatures.

factor roughly corresponds to the reduction expected from random projections of an hexagonal magnetoresistance tensor (preliminary measurements indicate that  $\Delta \rho/\rho$  is large only for  $I \parallel c$  and  $H \parallel c$ ).

As the residual resistivity  $\rho_0$  is much higher in single crystals than in polycrystals, one concludes that the very low temperature magnetoresistance is independent of  $\rho_0$ , i.e. dominated by its impurity part. Such a behavior agrees

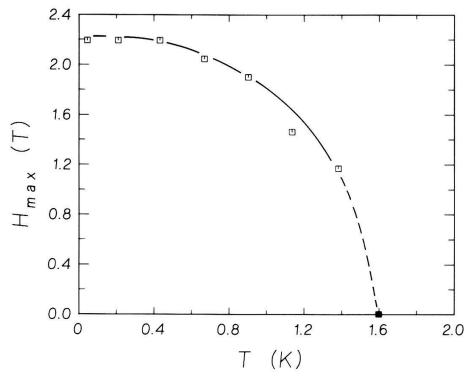


Figure 5 Magnetic phase diagram deduced from the magnetoresistance measurements.  $H_{\text{max}}$  is defined in Fig. 3.

with the above-mentioned two band model [17] and the maximum of  $\Delta \rho/\rho$  can be interpreted assuming the Fermi level is located in a pseudogap of the density of heavy states.

In fact, the positive magnetoresistance for I and  $H \parallel c$  can be observed up to 1.6 K, the temperature at which a break occurs in  $\rho_{\parallel}(T)$  (Fig. 2). Figure 5 shows the temperature variation of the crossover field  $H_{\text{max}}$ . Such a plot is strongly analogous to (H, T) phase diagrams of magnetic systems and then suggests some 'magnetic' phase in CeAl<sub>3</sub>. An appealing possibility is a magnetic order with very weak moments. Hence, the above-mentioned pseudogap in the density of heavy states which has been often presented as a characteristic of the Kondo resonance in the coherent state of HFC, might have a more conventional magnetic origin in CeAl<sub>3</sub>.

## **Conclusion**

To conclude we summarize our main results:

- the large anisotropy of the resistivity at temperatures higher than the CEF splitting underlines the anisotropy of the mixing interaction in the CeAl<sub>3</sub>
- the break of  $\rho_{\parallel}$  at 1.6 K, the  $T^3$  dependence of  $\rho_{\parallel}$  and  $\rho_{\perp}$  at lower temperature and the (H, T) phase diagram deduced from the magnetoresistance measurements give evidence of some kind of magnetic transition
- at very low temperature impurity scattering plays an essential role in transport properties.

The origin of the large residual resistivity of the single crystals is still not established. Chemical impurities can be ruled out since both single crystalline and polycrystalline samples were prepared from the same starting materials. Measurements of samples with small variations of composition have shown the insensibility of the residual resistance to stoichiometric deviations. Since the single crystalline grains result from recrystallization and are composed of nearly oriented small crystallites, stresses might be important in our single crystals. This possibility has to be studied further.

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